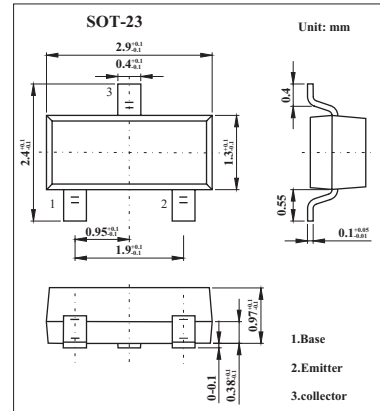


2SA1617

■ Features



■ Absolute Maximum Ratings Ta = 25°C

Parameter	Symbol	Rating	Unit
Collector-base voltage	V _{CB0}	-55	V
Collector-emitter voltage	V _{CEO}	-50	V
Emitter-base voltage	V _{EBO}	-5	V
Collector current	I _c	-100	mA
Collector dissipation	P _c	150	mW
Junction temperature	T _j	150	°C
Storage temperature	T _{stg}	-55 to +150	°C

■ Electrical Characteristics Ta = 25°C

Parameter	Symbol	Testconditons	Min	Typ	Max	Unit
Collector-base breakdown voltage	V _{(BR)CBO}	I _c = -10μA , I _E = 0	-55			V
Collector-emitter breakdown voltage	V _{(BR)CEO}	I _c = -1mA , R _{BE} = ∞	-50			V
Emitter-base breakdown voltage	V _{(BR)EBO}	I _E = -10μA , I _c = 0	-5			V
Collector cutoff current	I _{cBO}	V _{CB} = -30V , I _E =0			-0.5	μA
Emitter cutoff current	I _{EBO}	V _{EB} = -2V , I _c =0			-0.5	μA
DC current gain	h _{FE}	V _{CE} = -12V , I _c = -2mA	100		320	
Collector-emitter saturation voltage	V _{CE(sat)}	I _c = -10mA , I _B = -1mA			-0.2	V
Base-emitter voltage	V _{BE}	V _{CE} = -12V , I _c = -2mA			-0.8	V

■ hFE Classification

Marking	VI	
	B	C
hFE	100~200	160~320